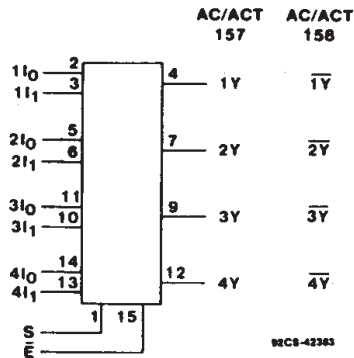




Data sheet acquired from Harris Semiconductor
SCHS283

CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158



FUNCTIONAL DIAGRAM

Quad 2-Input Multiplexers

AC/ACT157 - Non-Inverting

AC/ACT158 - Inverting

Type Features:

- Buffered inputs
- Typical propagation delay (AC/ACT158):
3.8 ns @ $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$

The RCA CD54/74AC157, -158 and CD54/74ACT157, -158 quad 2-input multiplexers use the RCA ADVANCED CMOS technology. Both circuits can select four bits of data from two sources under the control of a common select input (S). The Enable input ($\bar{E}$) is active LOW. When $\bar{E}$ is HIGH, all of the outputs of the 158 are forced HIGH and in the 157, all of the outputs are forced LOW, regardless of all other input conditions.

The CD74AC/ACT157 and CD74AC/ACT158 are supplied in 16-lead dual-in-line plastic packages (E suffix) and in 16-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to $+85^\circ\text{C}$); and Extended Industrial/Military (-55 to $+125^\circ\text{C}$).

The CD54AC157, -158 and CD54ACT157, -158, available in chip form (H suffix), are operable over the -55 to $+125^\circ\text{C}$ temperature range.

Family Features:

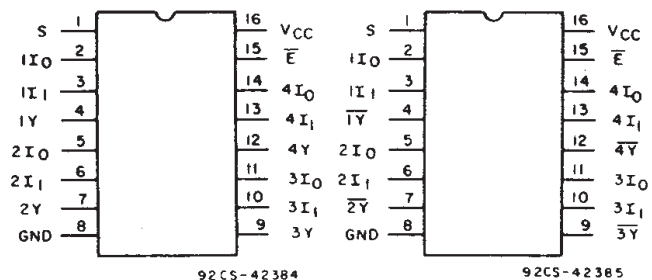
- Exceeds 2-kV ESD Protection - MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- $\pm 24\text{-mA}$ output drive current
 - Fanout to 15 FAST® ICs
 - Drives 50-ohm transmission lines

®FAST is a Registered Trademark of Fairchild Semiconductor Corp.

TRUTH TABLE

Enable	Select Input	Data Inputs		Output	
				157	158
$\bar{E}$	S	I_0	I_1	Y	$\bar{Y}$
H	X	X	X	L	H
L	L	L	X	L	H
L	L	H	X	H	L
L	H	X	L	L	H
L	H	X	H	H	L

H = High level, L = Low level, X = Don't care



92CS-42384

92CS-42385

CD54/74AC/ACT157

CD54/74AC/ACT158

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This data sheet is applicable to the CD54/74AC157 and CD74AC158. The CD54AC158, CD54ACT157, and CD54ACT158 were not acquired from Harris Semiconductor. See SCHS238 for information on the CD74ACT157 and CD74ACT158.

File Number 1910

CD54/74AC157, CD54/74AC158

CD54/74ACT157, CD54/74ACT158

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE (V_{CC})	-0.5 to 6 V
DC INPUT DIODE CURRENT, I_{IK} (for $V_i < -0.5$ V or $V_i > V_{CC} + 0.5$ V)	± 20 mA
DC OUTPUT DIODE CURRENT, I_{OK} (for $V_o < -0.5$ V or $V_o > V_{CC} + 0.5$ V)	± 50 mA
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I_o (for $V_o > -0.5$ V or $V_o < V_{CC} + 0.5$ V)	± 50 mA
DC V_{CC} or GROUND CURRENT (I_{CC} or I_{GND})	± 100 mA*
POWER DISSIPATION PER PACKAGE (P_D):	
For $T_A = -55$ to $+100^\circ\text{C}$ (PACKAGE TYPE E)	500 mW
For $T_A = +100$ to $+125^\circ\text{C}$ (PACKAGE TYPE E)	Derate Linearly at 8 mW/ $^\circ\text{C}$ to 300 mW
For $T_A = -55$ to $+70^\circ\text{C}$ (PACKAGE TYPE M)	400 mW
For $T_A = +70$ to $+125^\circ\text{C}$ (PACKAGE TYPE M)	Derate Linearly at 6 mW/ $^\circ\text{C}$ to 70 mW
OPERATING-TEMPERATURE RANGE (T_A)	-55 to $+125^\circ\text{C}$
STORAGE TEMPERATURE (T_{stg})	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 s maximum	$+265^\circ\text{C}$
Unit inserted into PC board min. thickness $1/16$ in. (1.59 mm) with solder contacting lead tips only	$+300^\circ\text{C}$

* For up to 4 outputs per device; add ± 25 mA for each additional output.

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range, V_{CC} *: (For T_A = Full Package-Temperature Range)			
AC Types	1.5	5.5	V
ACT Types	4.5	5.5	V
DC Input or Output Voltage, V_i , V_o	0	V_{CC}	V
Operating Temperature, T_A	-55	$+125$	$^\circ\text{C}$
Input Rise and Fall Slew Rate, dt/dv			
at 1.5 V to 3 V (AC Types)	0	50	ns/V
at 3.6 V to 5.5 V (AC Types)	0	20	ns/V
at 4.5 V to 5.5 V (ACT Types)	0	10	ns/V

* Unless otherwise specified, all voltages are referenced to ground.

CD54/74AC157, CD54/74AC158

CD54/74ACT157, CD54/74ACT158

STATIC ELECTRICAL CHARACTERISTICS: AC Series

CHARACTERISTICS	TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNITS
				+25		-40 to +85		-55 to +125		
	V _I (V)	I _O (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage V _{IH}			1.5	1.2	—	1.2	—	1.2	—	V
			3	2.1	—	2.1	—	2.1	—	
			5.5	3.85	—	3.85	—	3.85	—	
Low-Level Input Voltage V _{IL}			1.5	—	0.3	—	0.3	—	0.3	V
			3	—	0.9	—	0.9	—	0.9	
			5.5	—	1.65	—	1.65	—	1.65	
High-Level Output Voltage V _{OH}	V _{IH} or V _{IL}	-0.05	1.5	1.4	—	1.4	—	1.4	—	V
		-0.05	3	2.9	—	2.9	—	2.9	—	
		-0.05	4.5	4.4	—	4.4	—	4.4	—	
		-4	3	2.58	—	2.48	—	2.4	—	
		-24	4.5	3.94	—	3.8	—	3.7	—	
	#, * }	-75	5.5	—	—	3.85	—	—	—	
		-50	5.5	—	—	—	—	3.85	—	
Low Level Output Voltage V _{OL}	V _{IH} or V _{IL}	0.05	1.5	—	0.1	—	0.1	—	0.1	V
		0.05	3	—	0.1	—	0.1	—	0.1	
		0.05	4.5	—	0.1	—	0.1	—	0.1	
		12	3	—	0.36	—	0.44	—	0.5	
		24	4.5	—	0.36	—	0.44	—	0.5	
	#, * }	75	5.5	—	—	—	1.65	—	—	
		50	5.5	—	—	—	—	—	1.65	
Input Leakage Current I _I	V _{CC} or GND		5.5	—	±0.1	—	±1	—	±1	μA
Quiescent Supply Current, MSI I _{CC}	V _{CC} or GND	0	5.5	—	8	—	80	—	160	μA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

CHARACTERISTICS	TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNITS
				+25		-40 to +85		-55 to +125		
	V _I (V)	I _O (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage V _{IH}			4.5 to 5.5	2	—	2	—	2	—	V
Low-Level Input Voltage V _{IL}			4.5 to 5.5	—	0.8	—	0.8	—	0.8	V
High-Level Output Voltage V _{OH}	V _{IH} or V _{IL} #, * {	-0.05	4.5	4.4	—	4.4	—	4.4	—	V
		-24	4.5	3.94	—	3.8	—	3.7	—	
		-75	5.5	—	—	3.85	—	—	—	
		-50	5.5	—	—	—	—	3.85	—	
Low-Level Output Voltage V _{OL}	V _{IH} or V _{IL} #, * {	0.05	4.5	—	0.1	—	0.1	—	0.1	V
		24	4.5	—	0.36	—	0.44	—	0.5	
		75	5.5	—	—	—	1.65	—	—	
		50	5.5	—	—	—	—	—	1.65	
Input Leakage Current I _I	V _{CC} or GND		5.5	—	±0.1	—	±1	—	±1	μA
Quiescent Supply Current, MSI I _{CC}	V _{CC} or GND	0	5.5	—	8	—	80	—	160	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High 1 Unit Load ΔI _{CC}	V _{CC} -2.1		4.5 to 5.5	—	2.4	—	2.8	—	3	mA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOAD*	
	157	158
I (All)	0.37	0.37
$\bar{E}$	0.83	0.83
S	1.33	1.33

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

CD54/74AC157, CD54/74AC158

CD54/74ACT157, CD54/74ACT158

SWITCHING CHARACTERISTICS: AC Series; $t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C				UNITS	
			-40 to +85		-55 to +125			
			MIN.	MAX.	MIN.	MAX.		
Propagation Delays: Data to Output	(157)	t _{PLH} t _{PHL}	1.5 3.3* 5†	— 3.2 2.2	97 10.8 7.7	— 3 2.1	106 11.9 8.5	ns
Enable to Output	(157)	t _{PLH} t _{PHL}	1.5 3.3 5	— 5.1 3.6	154 17.2 12.3	— 4.7 3.4	169 18.9 13.5	ns
Select to Output	(157)	t _{PLH} t _{PHL}	1.5 3.3 5	— 5.4 3.8	164 18.5 13.2	— 5.1 3.6	180 20.3 14.5	ns
Data to Output	(158)	t _{PLH} t _{PHL}	1.5 3.3 5	— 3 2.2	91 12.8 7.3	— 2.8 2	100 11.2 8	ns
Enable to Output	(158)	t _{PLH} t _{PHL}	1.5 3.3 5	— 4.5 3.2	135 15.2 10.8	— 4.2 3	149 16.7 11.9	ns
Select to Output	(158)	t _{PLH} t _{PHL}	1.5 3.3 5	— 4.9 3.5	147 16.5 11.7	— 4.5 3.2	161 18.1 12.9	ns
Power Dissipation Capacitance	(157) (158)	C _{PD} §	—	156 Typ. 149 Typ.		156 Typ. 149 Typ.		pF
Input Capacitance		C _I	—	—	10	—	10	pF

SWITCHING CHARACTERISTICS: ACT Series; $t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C				UNITS
			-40 to +85		-55 to +125		
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: Data to Output	(157) t _{PLH} t _{PHL}	5†	2.5	8.6	2.4	9.5	ns
Enable to Output	(157) t _{PLH} t _{PHL}	5	3.6	12.3	3.4	13.5	ns
Select to Output	(157) t _{PLH} t _{PHL}	5	3.8	13.2	3.6	14.5	ns
Data to Output	(158) t _{PLH} t _{PHL}	5	2.4	8.4	2.3	9.2	ns
Enable to Output	(158) t _{PLH} t _{PHL}	5	3.3	11.3	3.1	12.4	ns
Select to Output	(158) t _{PLH} t _{PHL}	5	3.6	12.3	3.4	13.5	ns
Power Dissipation Capacitance	(157) (158) C _{PD} §	—	156 Typ. 149 Typ.		156 Typ. 149 Typ.		pF
Input Capacitance	C _I	—	—	10	—	10	pF

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*3.3 V: min. is @ 3.6 V
max. is @ 3 V

†5 V: min. is @ 5.5 V
max. is @ 4.5 V

$\S C_{PD}$ is used to determine the dynamic power consumption, per function.

For AC Series, $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o)$

For ACT Series, $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o) + V_{CC} \Delta I_{CC}$

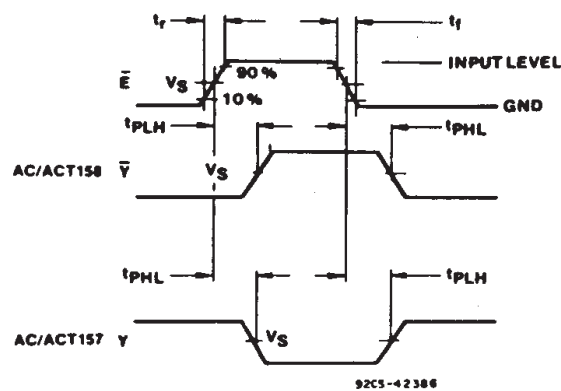
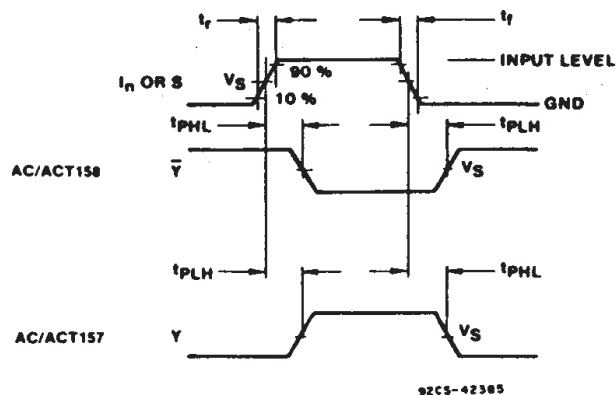
where f_i = input frequency

f_o = output frequency

C_L = output load capacitance

V_{CC} = supply voltage.

CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158



	CD54/74AC	CD54/74ACT
Input Level	V_{CC}	3 V
Input Switching Voltage, V_S	$0.5 V_{CC}$	1.5 V
Output Switching Voltage, V_S	$0.5 V_{CC}$	$0.5 V_{CC}$

Fig. 3 - Inputs or select to output propagation delays.

Fig. 4 - $\overline{\text{Enable}}$ to output propagation delays.

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